



**Supported by The Massie Chair of Excellence Program and DoE** 



**Advancements in Science** & Engineering:

**Fueling the Future** 

# **Multilayered Magnetic Structures**

# **Novelties & Future**

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March 26, 2009

# Outline

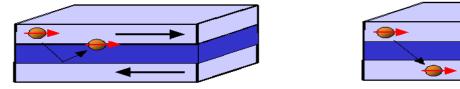
- Magnetic Multilayer Fundamentals
- $\succ$  A new paradigm  $\rightarrow$  Spintronics
- > Why my Hard Disk crashes?
- Magnetic multilayer research at UT

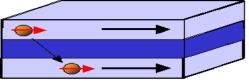


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# Fundamentals

A magnetic multilayer is any structure that includes two or more thin-films in which at least one is magnetic.





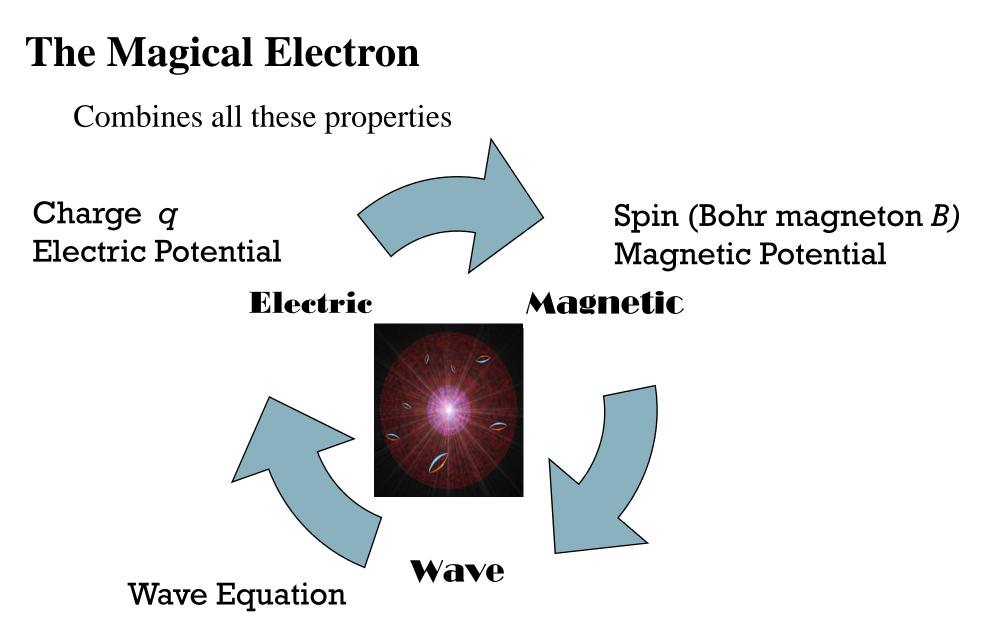
Magnetic multilayers exhibit **interesting electrical and magnetic properties**; these properties can be controlled giving rise to novel and useful devices.

#### Main controllable parameters:

- i. Direction of magnetization
- ii. Type of interacting materials
- iii. Thickness of interacting material



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Giant Magneto-resistance (GMR)

Tunnel Magneto-resistance (TMR)

Spin-valve Transistor

≻MRAM

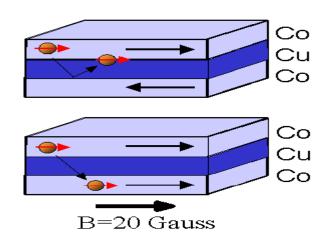




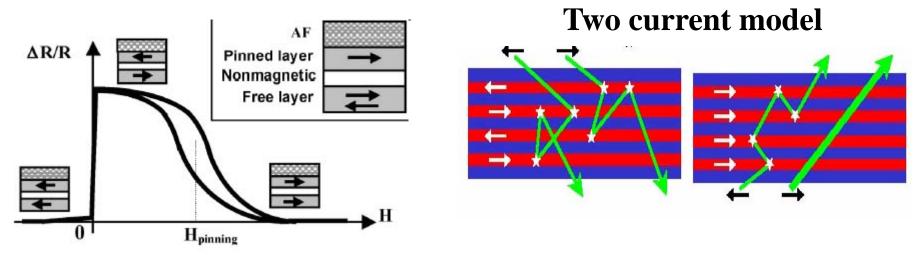
Giant Magneto-resistance (GMR)

- Tunnel Magneto-resistance (TMR)
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#### ≻MRAM



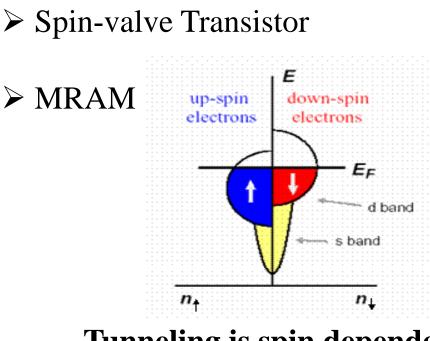
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Giant Magneto-resistance (GMR)

Tunnel Magneto-resistance (TMR)



free magnetic layer High insulating spacer Resistance Pinned magnetic layer N-Pinning antiferromagnetic layer tunneling current free magnetic layer Low insulating spacer Resistance Pinned magnetic laver N-Pinning antiferromagnetic layer tunneling current aka Magnetic Tunnel Junction

**Tunneling is spin dependent!** 

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(MTJ)



Giant Magneto-resistance (GMR)

Tunnel Magneto-resistance (TMR)

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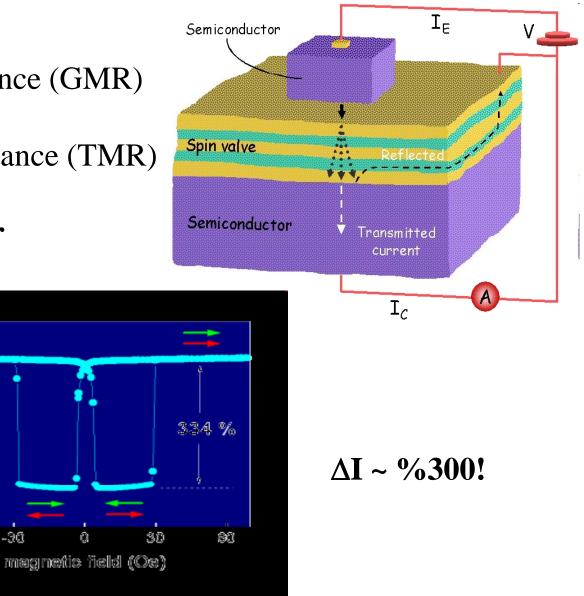
 $\mathbb{N}_{2}$ 

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> Spin-valve Transistor

collector current (nA)





≻MRAM

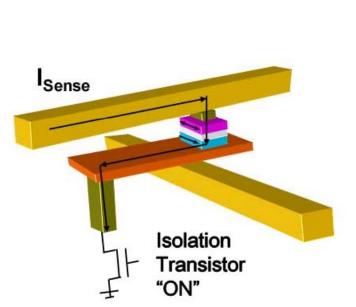
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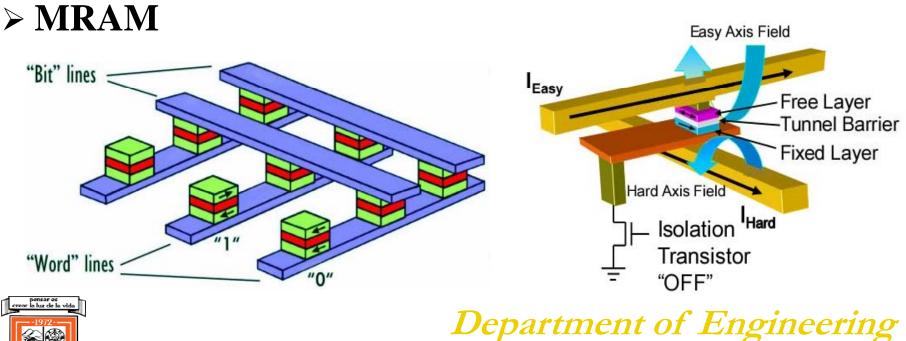
Yazan Hijazi - Massie Chair of Excellence Program @ UT

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Giant Magneto-resistance (GMR)

- Tunnel Magneto-resistance (TMR)
- Spin-valve Transistor







Giant Magneto-resistance (GMR)

- Tunnel Magneto-resistance (TMR)
- ≻ MRAM
- Spin-valve Transistor

**SPINTRONICS** 

#### Main challenge is maintaining polarized spin current!



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# Magnetic Multilayers @ Turabo

# **Students:**

- Raymond Borges
- Kevin Colon (Graduated and working)
- > Armando Velazquez

# **Collaborators:**

- > UPR
- > FIU
- University of California, Riverside

# **Capability:**

- Four target DC/RF magnetron sputtering system
- Lakeshore Guassmeter
- ≻Two Tesla electromagnet with bipolar power supply
- ► Lock-in amplifier







## Magnetic Multilayers @ Turabo

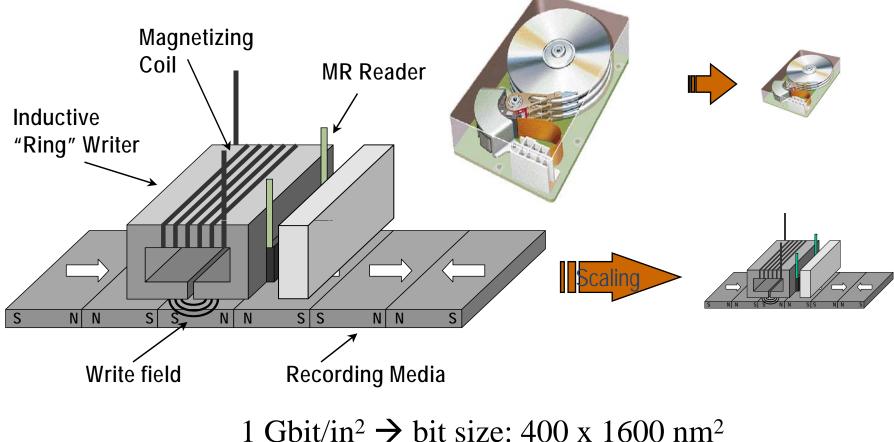
# Focus: Develop 3D magnetic media for Magnetic Storage Vertically integrated devices Use Gd within magnetic multilayers Radiation detection

So why does my hard disk crash?



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Traditionally, **Scaling Laws** were followed to advance data storage technologies

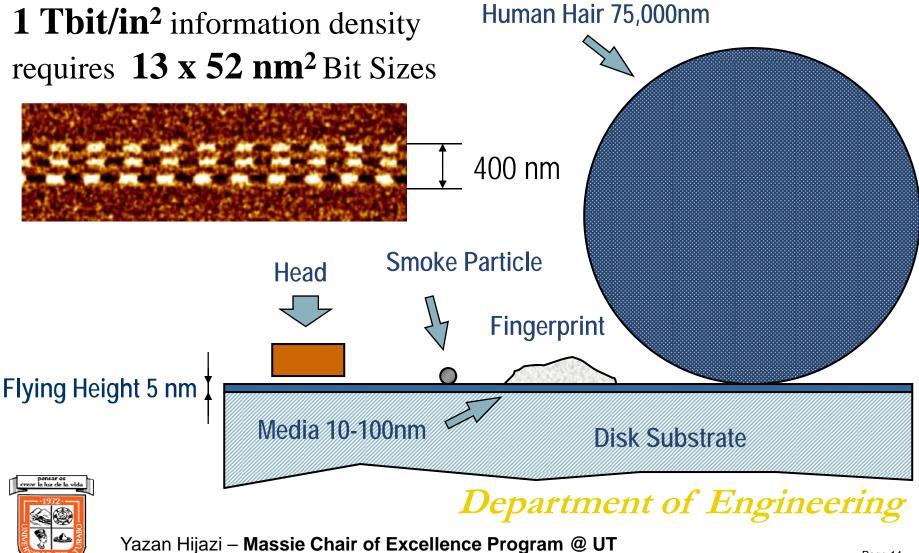


1 Gbit/in<sup>2</sup>  $\rightarrow$  bit size: 400 x 1600 nm<sup>2</sup> 100 Gbit/in<sup>2</sup>  $\rightarrow$  40 x 160 nm<sup>2</sup> 1 Tbit/in<sup>2</sup>  $\rightarrow$  13 x 52 nm<sup>2</sup>

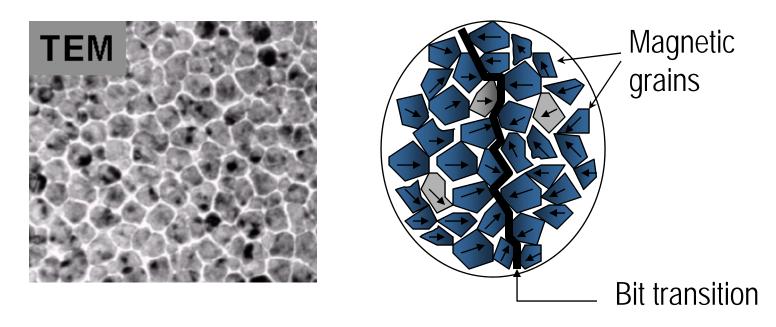


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#### Scaling $\rightarrow$ Smaller Transducers and Media



# **Superparamagnetic Limit**



#### SNR ~ log(N), N - number of grains per bit

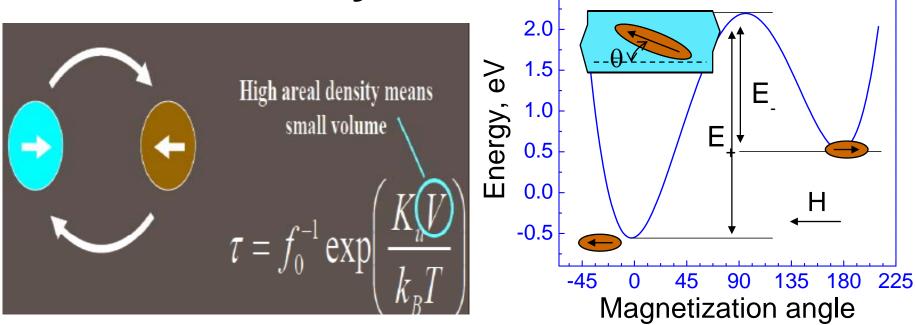
While scaling, need to preserve number of grains per bit to preserve SNRGrain size is reduced for higher areal densities:1

$$a \sim \frac{1}{\sqrt{Areal \ Density}}$$



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# Media Stability

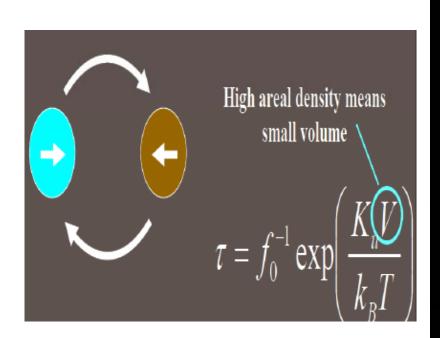


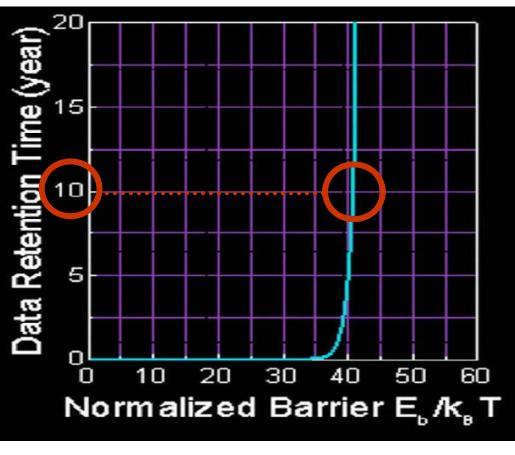
Thermally stable media: 
$$\frac{K_U V}{k_B T} > 40 - 60$$



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# **Media Stability**



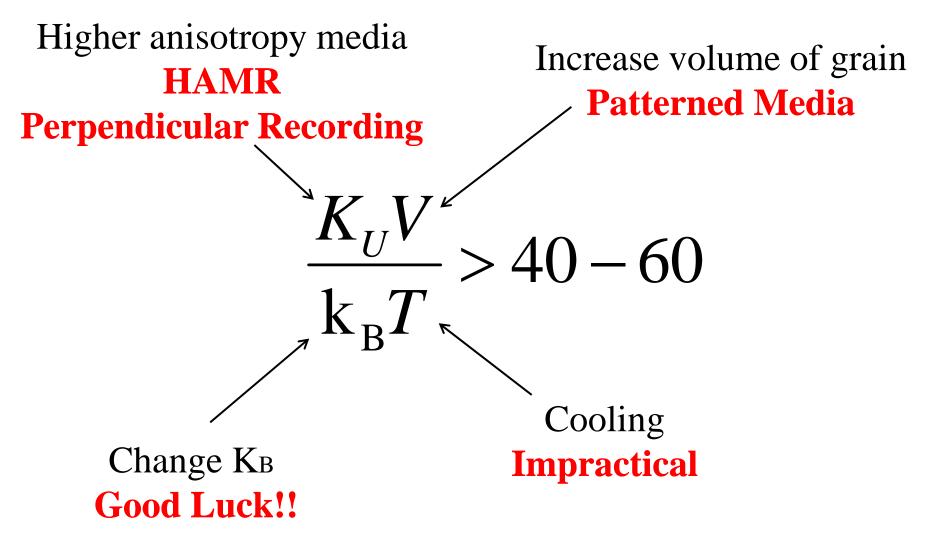


#### Thermally stable media:





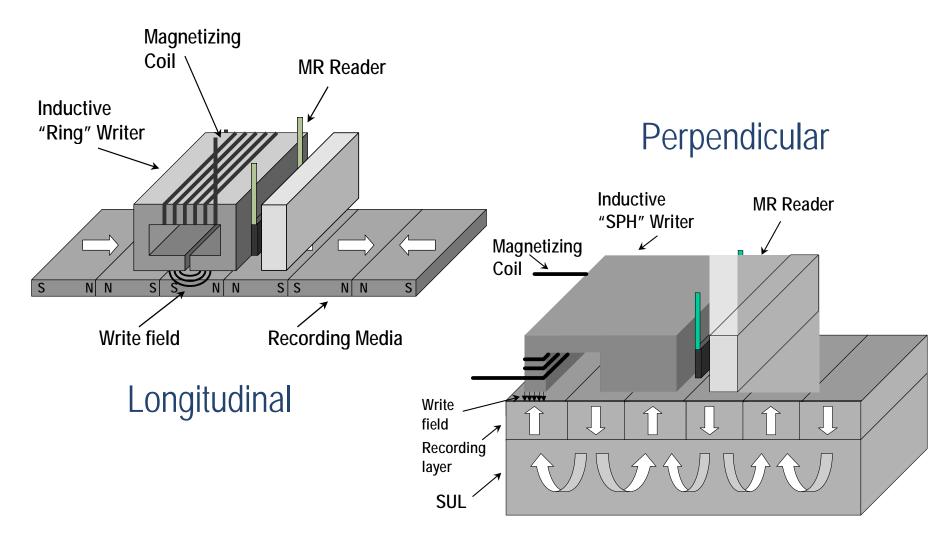
### What can be done?





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#### **Perpendicular Media** → **Narrow Transitions**





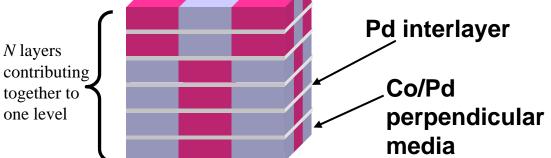
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## 3-D vs. Multilevel Magnetic Recording

Two potential implementations:

1. Multi-level Recording: not optimally utilized 3-D space

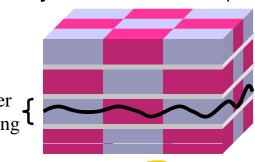
Note: Effective areal density increase is Log<sub>2</sub>L (where L is the number of signal levels)



2. 3-D Recording: each magnetic layer is separately addressed

Note: Effective areal density increase is **N** (where **N** is the number of recording layers)

*n*-th layer addressing **{** 



S. Khizroev, Y. Hijazi, N. Amos, R. Chomko, D. Litvinov, *Journal of Appied Physics*, 100, 63907 (2006).

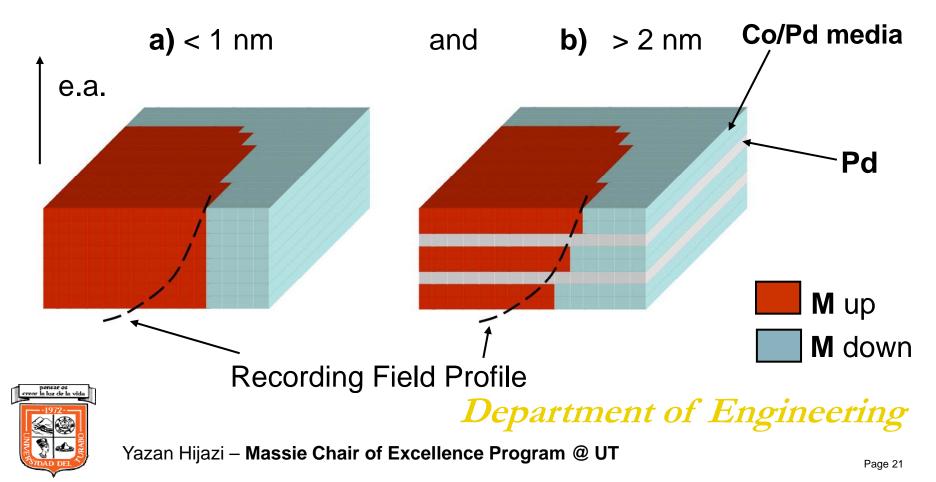
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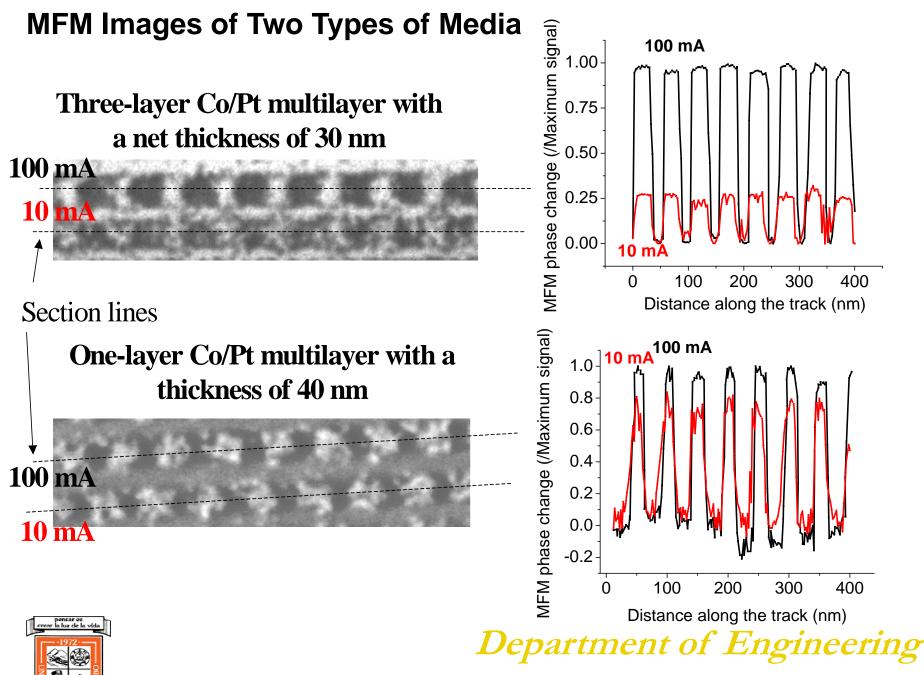


# Multi-level/3D Magnetic Media

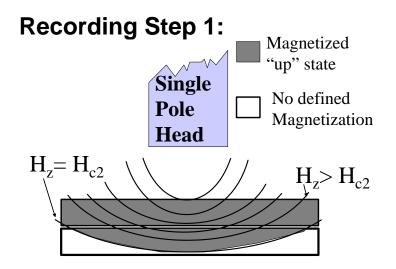
**Note:** The inter-layer separation should be sufficient to break the quantum-mechanical "exchange" coupling

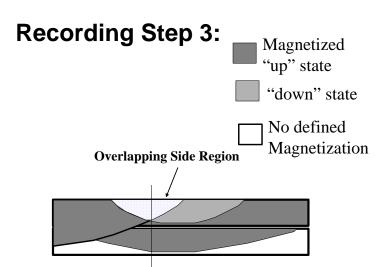
Micromagnetic Simulation Illustrating Two Cases of Interlayer Separation:

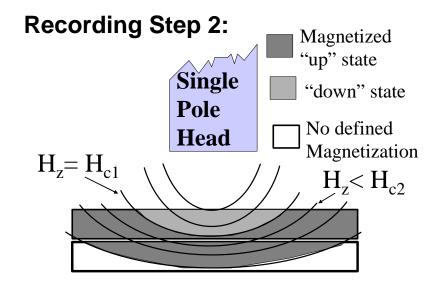




# **Multi-level Recording on a Continuous Medium**





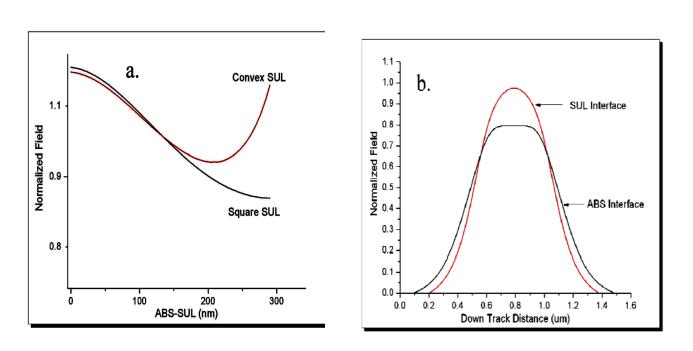


#### **Major Disadvantages:**

•Every time a track is recorded into the bottom layer, there are side regions in the top layer in which the earlier recorded information is lost because of the overlapping side region



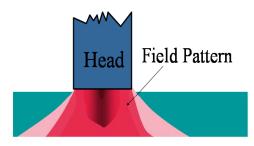
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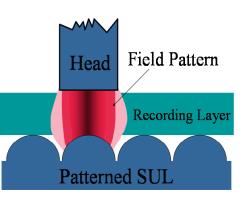


Y. Hijazi et. al. *IEEE Transactions on Magnetics*, vol. 42

(10), 2375-7, (2006).

#### **Patterned Soft Underlayer SUL**





#### Advantages:

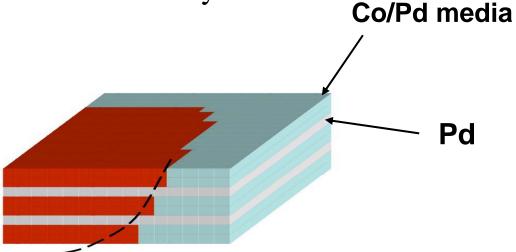
- 1. Increases SNR
- 2. Localized field
- 3. Improved field gradient



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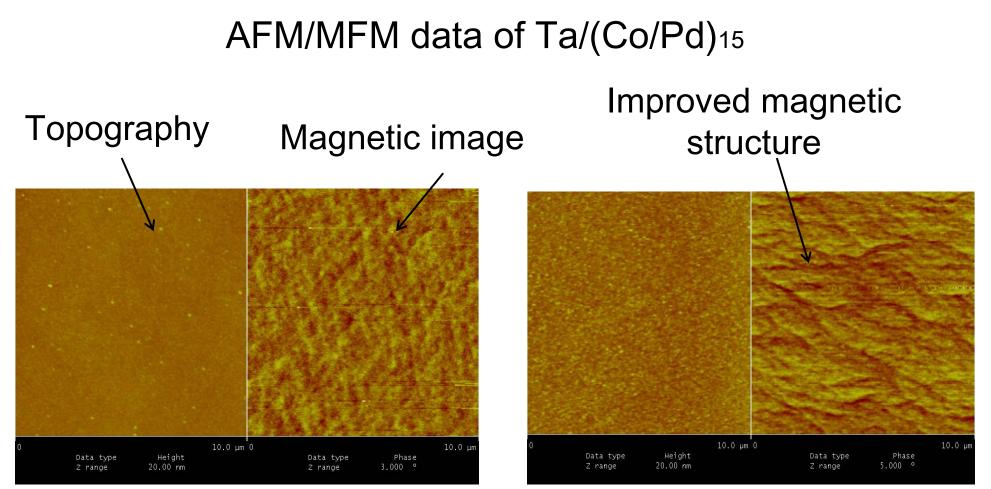
#### **3D Media Requirements**

- Perpendicular magnetic anisotropy
- > Patterned media  $\rightarrow$  improved SNR & areal density
- Magnetically insulated multilayers





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#### Ta thickness10nm

#### Ta thickness 40nm

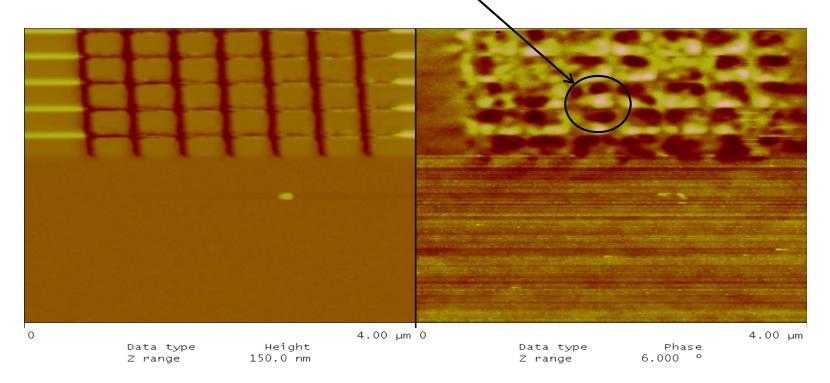
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Measurements done at Florida International University (FIU)

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## Single Layer (Co/Pd)15 400nm Island Size

Multi-domain



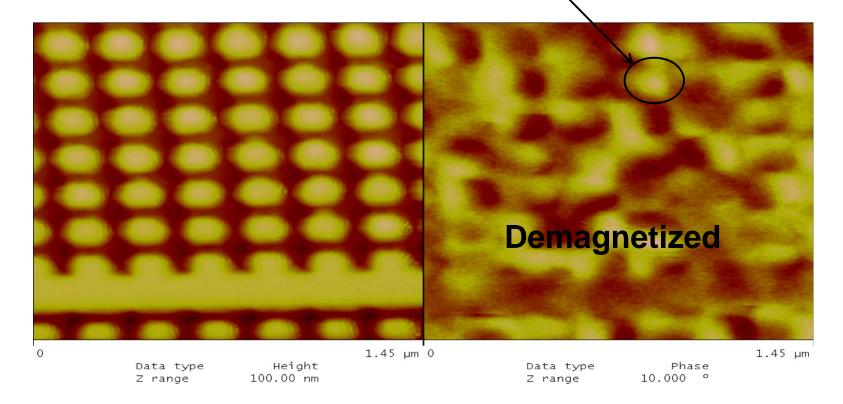
Measurements done at Florida International University (FIU) by Nissim Amos



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# Single Layer (Co/Pd)15 110nm Island Size

Single-domain



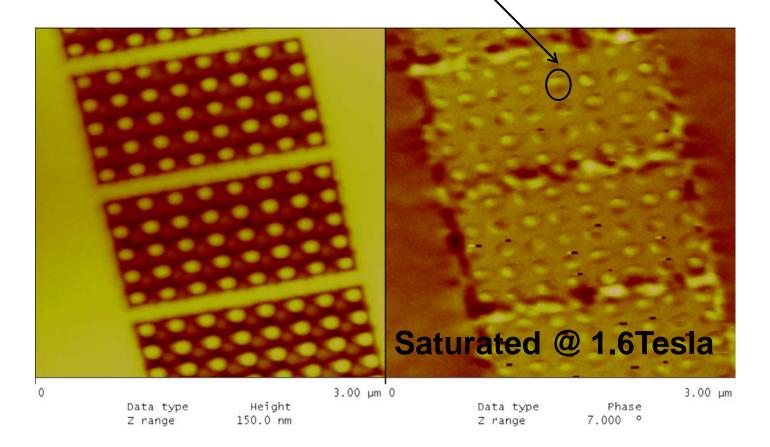
Measurements done at Florida International University (FIU) by Nissim Amos



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## Single Layer (Co/Pd)15 110nm Island Size

Single-domain





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# Summary

Magnetic multilayers are fundamental in novel applications utilizing the spin degree of freedom of the electron i.e. Spintronics.

Patterned magnetic multilayers offer unique advantages and will play a key role in future magnetic data storage systems.

>As Moore's law is exhausted it is time to stack things vertically to increase density and functionality  $\rightarrow$  3D magnetic media.

Universidad del Turabo has established in-house capability of producing structured magnetic multilayers for a wide variety of applications.



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#### **Thanks!**





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